

## [CLAIMS]

## [CLAIM 1]

A light emitting device is characterized by having

- 5            a first conductive film,
- an electrode comprising a second conductive film and a third conductive film provided so as to laminate with the first conductive film, and
- in the electrode,
- a lamination part of the first conductive film and the second conductive film functions as a source electrode, and
- 10          a lamination part of the first conductive film and the third conductive film functions as an electrode of a light emitting element.

## [CLAIM 2]

A light emitting device is characterized by having

- 15            a first conductive film,
- an electrode comprising a second conductive film and a third conductive film provided so as to laminate with the first conductive film, and
- in the electrode,
- a lamination part of the first conductive film and the second conductive film is adjacent to a source of a thin film transistor, and
- 20          a lamination part of the first conductive film and the third conductive film is adjacent to a light emitting layer.

## [CLAIM 3]

- 25          According to claim 1 or claim 2, the light emitting device is characterized in that the second conductive film is a film containing aluminum.

## [CLAIM 4]

A light emitting device is characterized by having

- 30            a first conductive film,
- an electrode comprising:
  - a second conductive film provided so as to laminate the first conductive film;
  - a third conductive film provided so as to overlap with the first conductive film; and
  - a fourth conductive film sandwiched between the first conductive film and the third conductive film, and
  - in the electrode,
  - a lamination part of first conductive film and the second conductive film functions as a source electrode, and
  - a lamination part of the first conductive film, the fourth conductive film, and the third conductive film functions as an electrode of a light emitting element.

## [CLAIM 5]

- 45          A light emitting device is characterized by having

a first conductive film;

an electrode comprising:

        a second conductive film provided so as to laminate with the first

conductive film;

a third conductive film provided so as to overlap with the first conductive film; and

5 a fourth conductive film sandwiched between the first conductive film and the third conductive film, and

in the electrode,

a lamination part of the first conductive film and the second conductive film is adjacent to a source electrode of a thin film transistor, and

10 a lamination part of the first conductive film, the fourth conductive film, and the third conductive film is adjacent to a light emitting layer.

**[CLAIM 6]**

According to claim 4 or claim 5, the light emitting device is characterized in that both of the second conductive film and the fourth conductive film are films containing aluminum.

**[CLAIM 7]**

A light emitting device is characterized by having

a first conductive film;

20 a second conductive film provided so as to laminate with the first conductive film;

a third conductive film; and

a fourth conductive film provided so as to laminate with the third conductive film, and

25 one of the third conductive film or the fourth conductive film is adjacent to the second conductive film,

a lamination part of the first conductive film and the second conductive film functions as a source electrode, and

30 a lamination part of the third conductive film and the fourth conductive film functions as an electrode of a light emitting element.

**[CLAIM 8]**

A light emitting device is characterized by having

a first conductive film;

35 a second conductive film provided so as to laminate with the first conductive film;

a third conductive film; and

a fourth conductive film provided so as to laminate with the third conductive film, and

40 one of the third conductive film or the fourth conductive film is adjacent to the second conductive film,

a lamination part of the first conductive film and the second conductive film is adjacent to a source electrode of a thin film transistor, and

45 a lamination part of the third conductive film and the fourth conductive film is adjacent to a light emitting layer.

**[CLAIM 9]**

According to claim 7 or claim 8, the light emitting device is characterized in that the second conductive film is a film containing aluminum.

**[CLAIM 10]**

A fabricating method of a light emitting device is characterized by the steps of  
5 forming an interlayer insulating film so as to cover a thin film transistor;  
forming a contact hole in the interlayer insulating film;  
forming a first conductive film and a second conductive film so as to cover the  
interlayer insulating film;  
selectively etching the second conductive film to process so as to cover a part  
of the first conductive film;  
10 forming the third conductive film so as to cover the first conductive film;  
processing the first conductive film with the use of a second mask and the third  
conductive film; and  
forming an electrode which comprises the first conductive film, the second  
conducting film, and the third conductive film, and functions as an electrode of a light  
15 emitting element.

**[CLAIM 11]**

According to claim 1 or claim 2, the fabricating method of a light emitting device is  
characterized in that the first conductive film comprises a reflection film, and the third  
20 conductive film comprises a transparent conductive film.

**[CLAIM 12]**

According to claim 1 or claim 2, the fabricating method of a light emitting device is  
characterized in that the third conductive film comprises a reflection film.

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**[CLAIM 13]**

According to claim 4 or claim 5, the fabricating method of a light emitting device is  
characterized in that the third conductive film comprises a reflection film, and the fourth  
conducting film comprises a transparent conductive film.

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**[CLAIM 14]**

An electronics device, wherein the light emitting device according to claim 1 or claim 2  
is mounted on a display portion.

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**[CLAIM 15]**

The electronics device according to claim 14 is an electronic device which is  
characterized by a display, a cellular phone, a Personal Digital Assistant, a television, or  
a monitor.

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**[CLAIM 16]**

An electronics device, wherein the light emitting device according to claim 4 or claim 5  
is mounted on a display portion.

**[CLAIM 17]**

45 The electronics device according to claim 16 is an electronic device which is  
characterized by a display, a cellular phone, a Personal Digital Assistant, a television, or  
a monitor.

**[CLAIM 18]**

An electronics device, wherein the light emitting device according to claim 7 or claim 8 is mounted on a display portion.

5   **[CLAIM 19]**

The electronics device according to claim 18 is an electronics device which is characterized by a display, a cellular phone, a Personal Digital Assistant, a television, or a monitor.

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